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# 3.3V CMOS 20-BIT BUFFER WITH 5 VOLT TOLERANT I/O

#### IDT74LVC16827A

# **FEATURES:**

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- · Supports hot insertion
- · Available in TSSOP package

#### **DRIVE FEATURES:**

- · High Output Drivers: ±24mA
- · Reduced system switching noise

## **APPLICATIONS:**

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

#### **DESCRIPTION:**

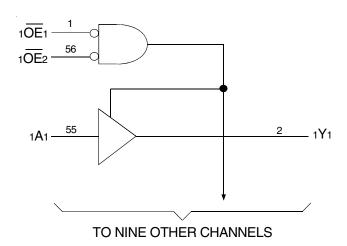
This 20-bit buffer is built using advanced dual metal CMOS technology. The LVC16827A provides high-performance bus interface buffering for wide data/address paths or buses carrying parity. Two pairs of NAND-ed output enable controls offer maximum control flexibility and are organized to operate the device as two 10-bit buffers or one 20-bit buffer. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

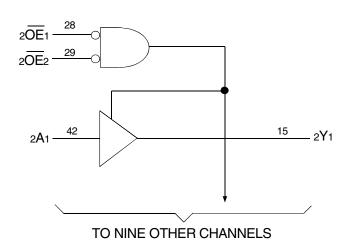
The LVC16827A buffer is ideally suited for driving high capacitance loads and low impedance backplanes.

All pins can be driven from either 3.3V or 5V devices. This feature allows the use of the device as a translator in a mixed 3.3V/5V supply system.

The LVC16827A has been designed with a  $\pm 24$ mA output driver. The driver is capable of driving a moderate to heavy load while maintaining speed performance.

#### **FUNCTIONAL BLOCK DIAGRAM**

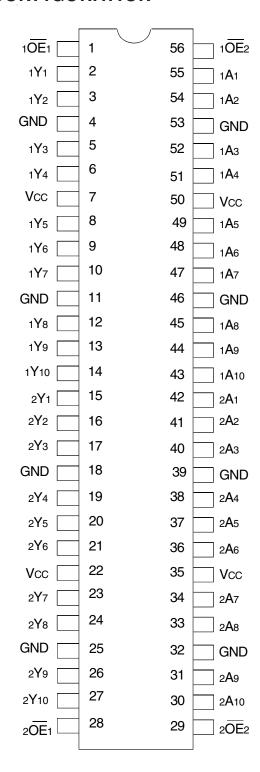




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**AUGUST 2015** 

## **PIN CONFIGURATION**



TSSOP TOP VIEW

# ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-50 to +50	mA
lik lok	Continuous Clamp Current, VI < 0 or Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

#### NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **CAPACITANCE** (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	рF
Соит	Output Capacitance	Vout = 0V	6.5	8	рF
Cı/o	I/O Port Capacitance	VIN = 0V	6.5	8	pF

#### NOTE:

1. As applicable to the device type.

# **PIN DESCRIPTION**

Pin Names	Description
xŌĒx	Output Enable Inputs (Active LOW)
xAx	Data Inputs
xYx	3-State Outputs

## **FUNCTION TABLE**(1)

Inputs			Outputs
x <del>OE</del> 1	x <del>OE</del> 2	xAx	хҮх
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z

#### NOTE:

- 1. H = HIGH Voltage Level
  - L = LOW Voltage Level
  - X = Don't Care
  - Z = High Impedance

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Te	st Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
lih lil	Input Leakage Current	Vcc = 3.6V	V <sub>I</sub> = 0 to 5.5V	_	_	±5	μΑ
lozh lozl	High Impedance Output Current (3-State Output pins)	Vcc = 3.6V	Vo = 0 to 5.5V	_	_	±10	μΑ
loff	Input/Output Power Off Leakage	$Vcc = 0V$ , $Vin or Vo \le 5$	.5V	_	_	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		_	-0.7	-1.2	V
VH	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL ICCH	Quiescent Power Supply Current	Vcc = 3.6V	Vin = GND or Vcc	_	_	10	μΑ
Iccz		$3.6 \le VIN \le 5.5V^{(2)}$			_	10	
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, o	other inputs at Vcc or GND	_	_	500	μA

#### NOTES:

- 1. Typical values are at Vcc = 3.3V, +25°C ambient.
- 2. This applies in the disabled state only.

# **OUTPUT DRIVE CHARACTERISTICS**

Symbol	Parameter	Test C	Test Conditions <sup>(1)</sup>		Max.	Unit
Vон	Output HIGH Voltage Vcc = 2.3V to 3.6V	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = − 6mA	2	_	
		Vcc = 2.3V	IOH = - 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V		2.4	_	
		Vcc = 3V	Iон = - 24mA	2.2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 6mA	_	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3V	IoL = 24mA		0.55	

#### NOTE:

<sup>1.</sup> VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.

# OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, Ta = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Buffer/Driver Outputs enabled	CL = 0pF, f = 10Mhz		pF
CPD	Power Dissipation Capacitance per Buffer/Driver Outputs disabled			

# **SWITCHING CHARACTERISTICS**(1)

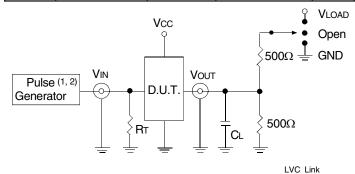
		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	1.5	4.7	1.5	4.1	ns
tPHL	xAx to xYx					
tpzh	Output Enable Time	1.5	6.5	1.5	5.8	ns
tpzl.	xOEx to xYx					
tPHZ	Output Disable Time	1.5	6.4	1.5	5.7	ns
tPLZ	xOEx to xYx					
tsk(o)	Output Skew <sup>(2)</sup>	_	_	_	500	ps

#### NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS.  $TA = -40^{\circ}C$  to  $+85^{\circ}C$ .
- 2. Skew between any two outputs of the same package and switching in the same direction.

# TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	Vcc <sup>(1)</sup> =3.3V±0.3V	Vcc <sup>(1)</sup> =2.7V	Vcc <sup>(2)</sup> =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
VIH	2.7	2.7	Vcc	V
VT	1.5	1.5	Vcc/2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



Test Circuit for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

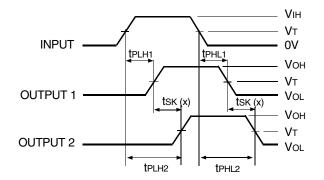
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

#### NOTES:

- 1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

# **SWITCH POSITION**

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open

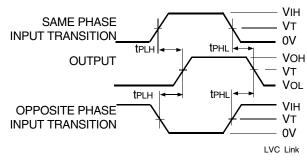


tsk(x) = |tplh2 - tplh1| or |tphl2 - tphl1|

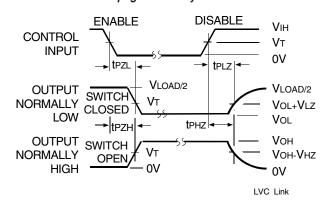
Output Skew - tsk(x)

#### NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



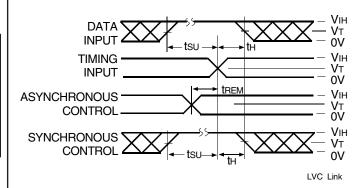
#### Propagation Delay



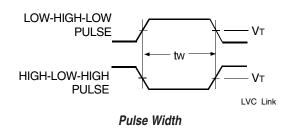
#### **Enable and Disable Times**

#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

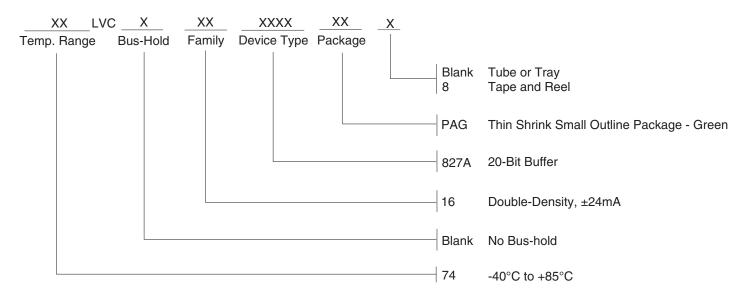


#### Set-up, Hold, and Release Times



LVC Link

## **ORDERING INFORMATION**



## DATASHEET DOCUMENT HISTORY

08/20/2015 Pg. 6 Updated the ordering information by removing non RoHS parts and adding Tape and Reel information.



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